

■ Features

- High isolation 5000 VRMS
- DC input with logic gate output
- Operating temperature range - 55 °C to 110 °C
- RoHS & REACH Compliance
- Halogen free
- MSL class 1
- Regulatory Approvals
 - UL - UL1577
 - VDE - EN60747-5-5(VDE0884-5)
 - CQC – GB4943.1, GB8898

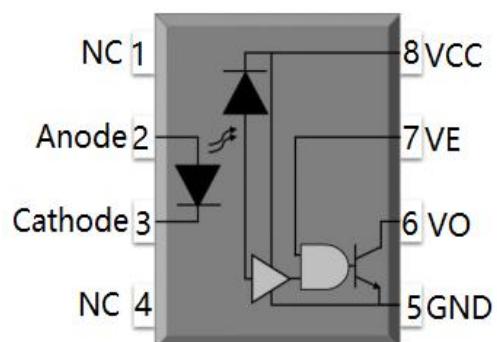
■ Applications

- Ground loop elimination
- LSTTL to TTL, LSTTL or CMOS
- Line receiver, data transmission
- Data multiplexing
- Switching power supply
- Pulse transformer replacement
- Computer-peripheral interface

■ Description

The 6N137, MPC2601, MPC2611 series combine an AlGaAs infrared emitting diode as the emitter which is optically coupled to a silicon high speed integrated photo-detector logic gate with a strobable output in a plastic DIP8 package with different lead forming options.

■ Schematic





ABSOLUTE MAXIMUM RATINGS

PARAMETER	SYMBOL	VALUE	UNIT	Note
INPUT				
Forward Current	I _F	25	mA	
Peak Forward Current	I _{FP}	50	mA	1
Peak Transient Current	I _{F(trans)}	1	A	2
Reverse Voltage	V _R	5	V	
Enable Voltage	V _E	VCC+0.5	V	
Input Power Dissipation	P _I	100	mW	
OUTPUT				
Supply Voltage	V _{CC}	7	V	
Output Voltage	V _O	7	V	
Output Current	I _O	50	mA	
Output Power Dissipation	P _O	85	mW	
COMMON				
Total Power Dissipation	P _{tot}	200	mW	
Isolation Voltage	V _{iso}	5000	Vrms	3
Operating Temperature	T _{opr}	-55~100	°C	
Storage Temperature	T _{stg}	-55~125	°C	
Soldering Temperature	T _{sol}	260	°C	4

Note 1. 50% duty, 1ms P.W

Note 2. ≤1μs P.W, 300pps

Note 3. AC For 1 Minute, R.H. = 40 ~ 60%

Note 4. For 10 seconds



RECOMMENDED OPERATION CONDITIONS				
PARAMETER	SYMBOL	MIN.	MAX.	UNIT
Operating Temperature	TA	-40	100	°C
Supply Voltage	VCC	2.7	3.6	V
	VCC	4.5	5.5	V
Low Level Input Current	IFL	0	250	µA
High Level Input Current	IFH	5	15	mA
Low Level Enable Voltage	VEL	0	0.8	V
High Level Enable Voltage	VEH	2	VCC	V
Output Pull-up Resistor	RL	330	4k	Ω
Fan Out (at RL=1kΩ per channel)	N	-	5	TTL Loads

ELECTRICAL OPTICAL CHARACTERISTICS at Ta=25°C						
PARAMETER	SYMBOL	MIN.	Typ.	MAX.	UNIT	TEST CONDITION
INPUT						
Forward Voltage	V _F	-	1.38	1.8	V	I _F =10mA
Reverse Current	I _R	-	-	10	µA	V _R =5V
Input Capacitance	C _{in}	-	13	-	pF	V=0, f=1MHz
OUTPUT						
High Level Supply Current	I _{CCH}	-	6.3	10	mA	I _F =0mA, V _E =0.5V, V _{CC} =5.5V
Low Level Supply Current	I _{CCL}	-	8.3	13	mA	I _F =10mA, V _{CC} =5.5V
High Level Enable Current	I _{EH}	-	-0.52	-1.6	mA	V _E =2.0V, V _{CC} =5.5V
Low Level Enable Current	I _{EL}	-	-0.75	-1.6	mA	V _E =0.5V, V _{CC} =5.5V
High Level Enable Voltage	V _{EH}	2.0	-	-	V	I _F =10mA, V _{CC} =5.5V
Low Level Enable Voltage	V _{EL}	-	-	0.8	V	I _F =10mA, V _{CC} =5.5V
TRANSFER CHARACTERISTICS (Ta=-40 to 85°C)						
High Level Output Current	I _{OH}	-	0.73	100	µA	V _{CC} =5.5V, V _O =5.5V, I _F =250µA, V _E =2.0V
Low Level Output Voltage	V _{OL}	-	0.28	0.6	V	V _{CC} =5.5V, I _F =5mA, V _E =2.0V, I _{CL} =13mA
Input Threshold Current	I _{FT}	-	2.5	5	mA	V _{CC} =5.5V, V _O =0.6V, V _E =2.0V, I _{OL} =13mA
Isolation Resistance	R _{iso}	10 ¹²	10 ¹⁴	-	Ω	DC500V, 40 ~ 60% R.H.
Floating Capacitance	C _{io}	-	1.0	-	pF	V=0, f=1MHz



ELECTRICAL OPTICAL CHARACTERISTICS							
PARAMETER	SYMBOL	MIN.	TYP.	MAX.	UNIT	TEST CONDITION	NOTE
SWITCHING CHARACTERISTICS ($T_a = -40$ to $85^\circ C$, $V_{CC} = 5V$, $I_F = 7.5mA$ unless specified otherwise)							
Propagation Delay Time to Output Low Level	TPHL	-	35	75	ns	$C_L = 15pF$, $R_L = 350\Omega$, $T_a = 25^\circ C$	
Propagation Delay Time to Output High Level	TPLH	-	40	75	ns	$C_L = 15pF$, $R_L = 350\Omega$, $T_a = 25^\circ C$	
Pulse Width Distortion	TPHL-TPLH	-	5	35	ns	$C_L = 15pF$, $R_L = 350\Omega$	
Rise Time	tr	-	27	-	ns	$C_L = 15pF$, $R_L = 350\Omega$	
Fall Time	tf	-	7	-	ns	$C_L = 15pF$, $R_L = 350\Omega$	
Enable Propagation Delay Time to Output Low Level	TEHL	-	15	-	ns	$I_F = 7.5mA$, $V_{EH} = 3.5V$, $C_L = 15pF$, $R_L = 350\Omega$	
Enable Propagation Delay Time to Output High Level	TELH	-	15	-	ns	$I_F = 7.5mA$, $V_{EH} = 3.5V$, $C_L = 15pF$, $R_L = 350\Omega$	
Common Mode Transient Immunity at Logic High	6N137	CMH	-	-	-	V/ μ s	$I_F = 7.5mA$, $V_{OH} = 2.0V$, $R_L = 350\Omega$, $T_a = 25^\circ C$ $V_{CM} = 10Vp-p$
	MPC2601		5000	-	-		$I_F = 7.5mA$, $V_{OH} = 2.0V$, $R_L = 350\Omega$, $T_a = 25^\circ C$ $V_{CM} = 50Vp-p$
	MPC2611		10000	-	-		$I_F = 7.5mA$, $V_{OH} = 2.0V$, $R_L = 350\Omega$, $T_a = 25^\circ C$ $V_{CM} = 400Vp-p$
Common Mode Transient Immunity at Logic Low	6N137	CML	-	-	-	V/ μ s	$I_F = 0mA$, $V_{OH} = 0.8V$, $R_L = 350\Omega$, $T_a = 25^\circ C$ $V_{CM} = 10Vp-p$
	MPC2601		5000	-	-		$I_F = 0mA$, $V_{OH} = 0.8V$, $R_L = 350\Omega$, $T_a = 25^\circ C$ $V_{CM} = 50Vp-p$
	MPC2611		10000	-	-		$I_F = 0mA$, $V_{OH} = 0.8V$, $R_L = 350\Omega$, $T_a = 25^\circ C$ $V_{CM} = 400Vp-p$

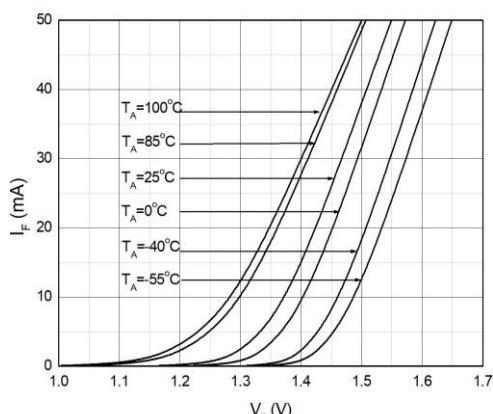
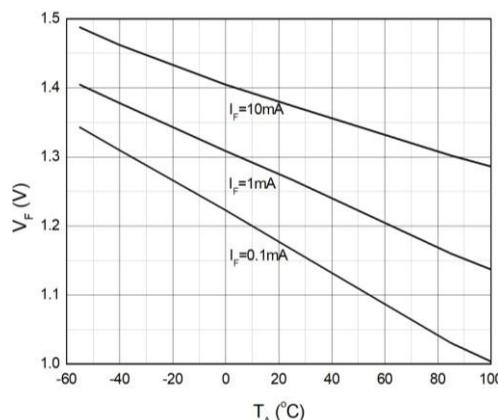
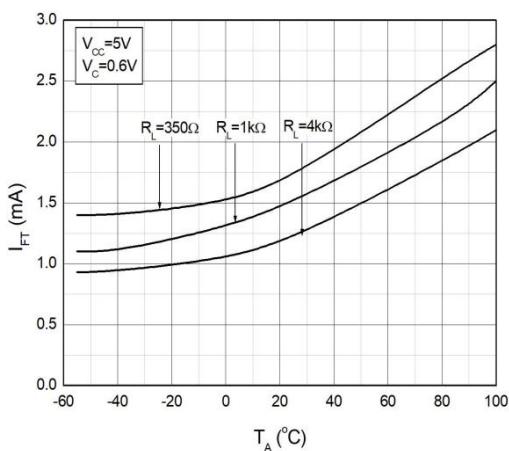
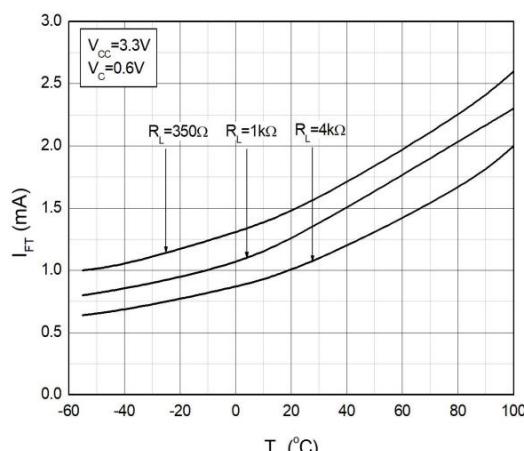
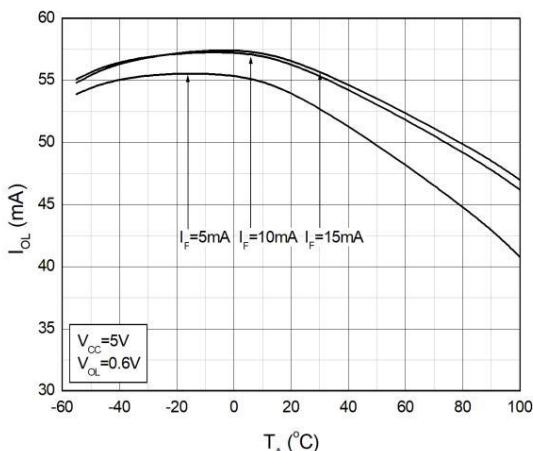
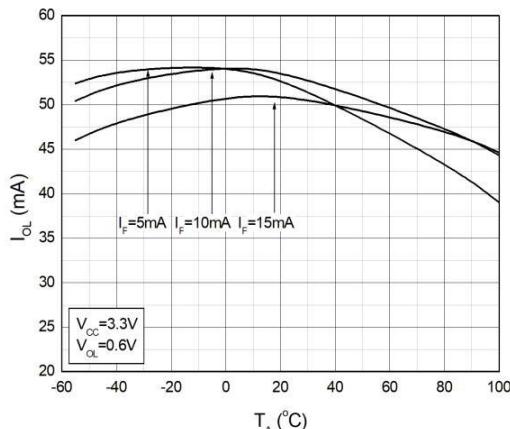


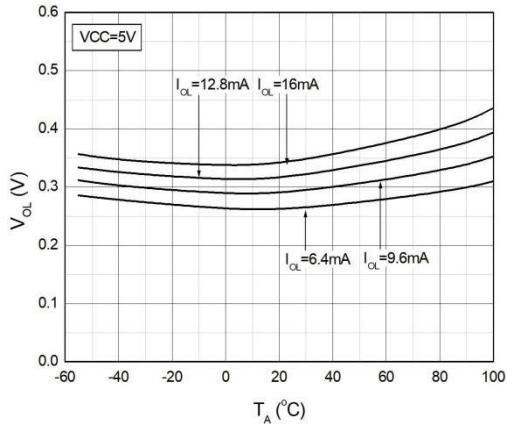
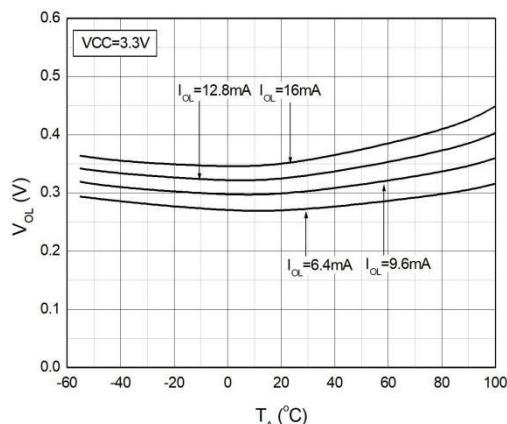
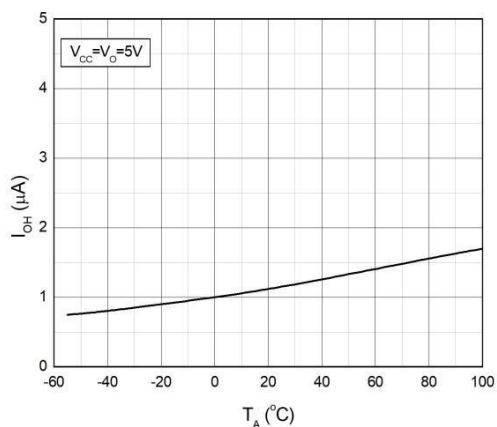
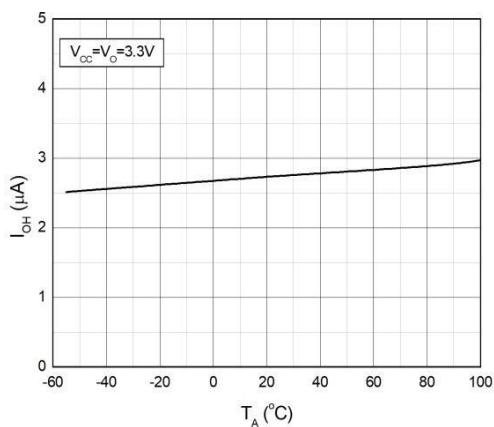
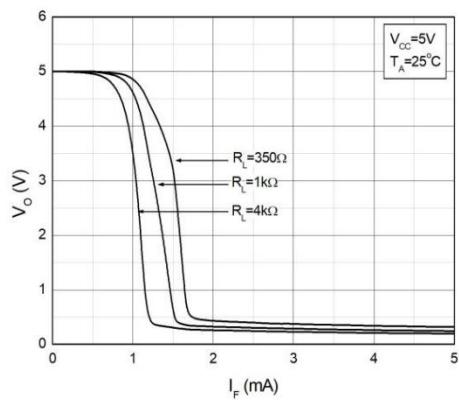
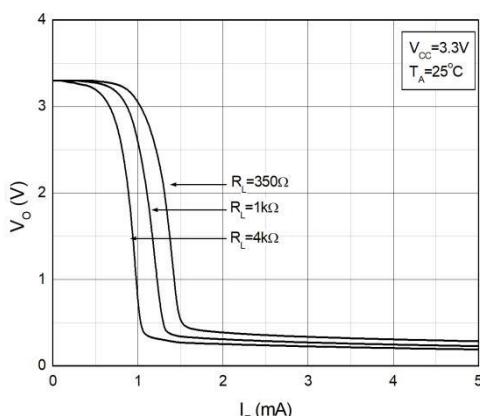
ELECTRICAL OPTICAL CHARACTERISTICS at Ta=25°C

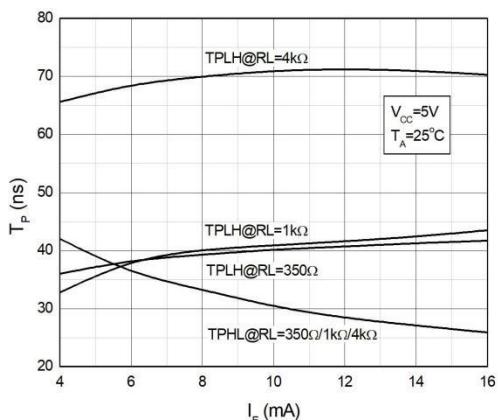
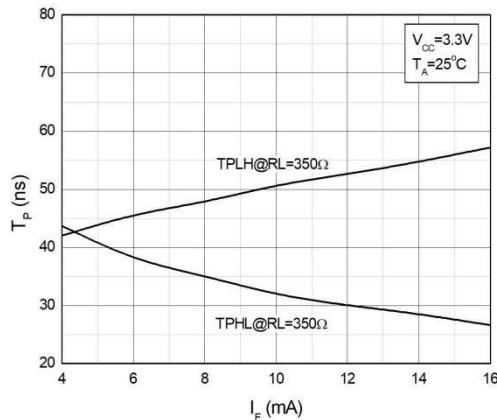
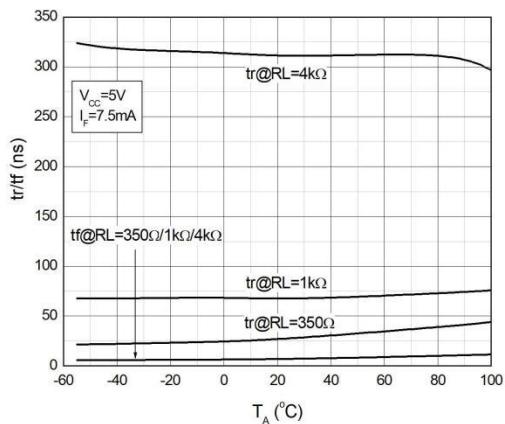
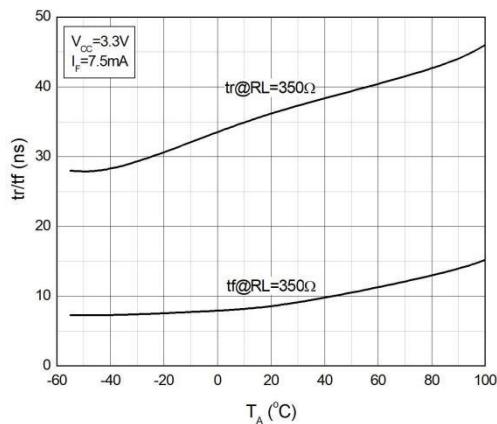
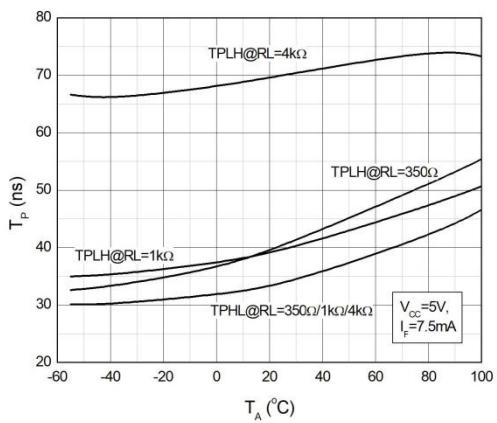
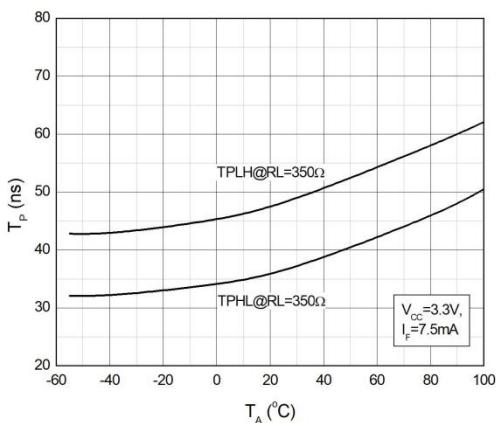
PARAMETER	SYMBOL	MIN.	TYP.	MAX.	UNIT	TEST CONDITION	NOTE
INPUT							
Forward Voltage	V _F	-	1.38	1.8	V	I _F =10mA	
Reverse Current	I _R	-	-	10	μA	V _R =5V	
Input Capacitance	C _{in}	-	13	-	pF	V=0, f=1MHz	
OUTPUT							
High Level Supply Current	I _{CCH}	-	4.3	10	mA	I _F =0mA, V _E =0.5V, V _{CC} =3.3V	
Low Level Supply Current	I _{CCL}	-	6.4	13	mA	I _F =10mA, V _{CC} =3.3V	
High Level Enable Current	I _{EH}	-	-0.21	-1.6	mA	V _E =2.0V, V _{CC} =3.3V	
Low Level Enable Current	I _{EL}	-	-0.42	-1.6	mA	V _E =0.5V, V _{CC} =3.3V	
High Level Enable Voltage	V _{EH}	2.0	-	-	V	I _F =10mA, V _{CC} =3.3V	
Low Level Enable Voltage	V _{EL}	-	-	0.8	V	I _F =10mA, V _{CC} =3.3V	
TRANSFER CHARACTERISTICS (Ta=-40 to 85°C)							
High Level Output Current	I _{OH}	-	4.1	100	μA	V _{CC} =3.3V, V _O =3.3V, I _F =250μA, V _E =2.0V	
Low Level Output Voltage	V _{OL}	-	0.29	0.6	V	V _{CC} =3.3V, I _F =5mA, V _E =2.0V, I _{CL} =13mA	
Input Threshold Current	I _{FT}	-	2.2	5	mA	V _{CC} =3.3V, V _O =0.6V, V _E =2.0V, I _{OL} =13mA	
Isolation Resistance	R _{iso}	10 ¹²	10 ¹⁴	-	Ω	DC500V, 40 ~ 60% R.H.	
Floating Capacitance	C _{lo}	-	1.0	-	pF	V=0, f=1MHz	



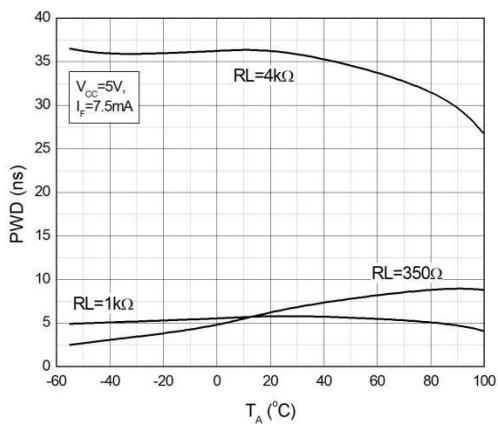
ELECTRICAL OPTICAL CHARACTERISTICS							
PARAMETER	SYMBOL	MIN.	TYP.	MAX.	UNIT	TEST CONDITION	NOTE
SWITCHING CHARACTERISTICS ($T_a = -40$ to $85^\circ C$, $V_{CC} = 3.3V$, $I_F = 7.5mA$ unless specified otherwise)							
Propagation Delay Time to Output Low Level	TPHL	-	35	75	ns	$C_L = 15pF$, $R_L = 350\Omega$, $T_a = 25^\circ C$	
Propagation Delay Time to Output High Level	TPLH	-	47	75	ns	$C_L = 15pF$, $R_L = 350\Omega$, $T_a = 25^\circ C$	
Pulse Width Distortion	TPHL-TPLH	-	12	35	ns	$C_L = 15pF$, $R_L = 350\Omega$	
Rise Time	tr	-	30	-	ns	$C_L = 15pF$, $R_L = 350\Omega$	
Fall Time	tf	-	8.5	-	ns	$C_L = 15pF$, $R_L = 350\Omega$	
Enable Propagation Delay Time to Output Low Level	TEHL	-	15	-	ns	$I_F = 7.5mA$, $V_{EH} = 3.3.3V$, $C_L = 15pF$, $R_L = 350\Omega$	
Enable Propagation Delay Time to Output High Level	TELH	-	15	-	ns	$I_F = 7.5mA$, $V_{EH} = 3.3.3V$, $C_L = 15pF$, $R_L = 350\Omega$	
Common Mode Transient Immunity at Logic High	6N137	CMH	-	-	-	V/ μ s	$I_F = 7.5mA$, $V_{OH} = 2.0V$, $R_L = 350\Omega$, $T_a = 25^\circ C$ $V_{CM} = 10Vp-p$
	MPC2601		5000	-	-		$I_F = 7.5mA$, $V_{OH} = 2.0V$, $R_L = 350\Omega$, $T_a = 25^\circ C$ $V_{CM} = 50Vp-p$
	MPC2611		10000	-	-		$I_F = 7.5mA$, $V_{OH} = 2.0V$, $R_L = 350\Omega$, $T_a = 25^\circ C$ $V_{CM} = 400Vp-p$
Common Mode Transient Immunity at Logic Low	6N137	CML	-	-	-	V/ μ s	$I_F = 0mA$, $V_{OH} = 0.8V$, $R_L = 350\Omega$, $T_a = 25^\circ C$ $V_{CM} = 10Vp-p$
	MPC2601		5000	-	-		$I_F = 0mA$, $V_{OH} = 0.8V$, $R_L = 350\Omega$, $T_a = 25^\circ C$ $V_{CM} = 50Vp-p$
	MPC2611		10000	-	-		$I_F = 0mA$, $V_{OH} = 0.8V$, $R_L = 350\Omega$, $T_a = 25^\circ C$ $V_{CM} = 400Vp-p$

CHARACTERISTIC CURVES

**Fig.1 Forward Current
vs. Forward Voltage**

**Fig.2 Forward Voltage
vs. Ambient Temperature**

**Fig.3 Input Threshold Current
vs. Ambient Temperature**

**Fig.4 Input Threshold Current
vs. Ambient Temperature**

**Fig.5 Low Level Output Current
vs. Ambient Temperature**

**Fig.6 Low Level Output Current
vs. Ambient Temperature**

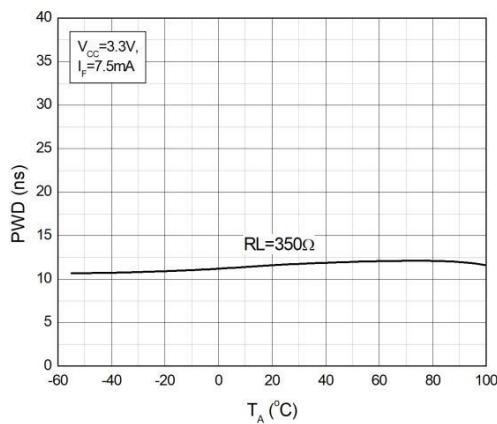
CHARACTERISTIC CURVES

Fig.7 Low Level Output Voltage vs. Ambient Temperature

Fig.8 Low Level Output Voltage vs. Ambient Temperature

Fig.9 High Level Output Current vs. Ambient Temperature

Fig.10 High Level Output Current vs. Ambient Temperature

Fig.11 Output Voltage vs. Forward Current

Fig.12 Output Voltage vs. Forward Current

CHARACTERISTIC CURVES

**Fig.13 Propagation Delay
vs. Forward Current**

**Fig.14 Propagation Delay
vs. Forward Current**

**Fig.15 Rise and Fall Time
vs. Ambient Temperature**

**Fig.16 Rise and Fall Time
vs. Ambient Temperature**

**Fig.17 Propagation Delay
vs. Ambient Temperature**

**Fig.18 Propagation Delay
vs. Ambient Temperature**

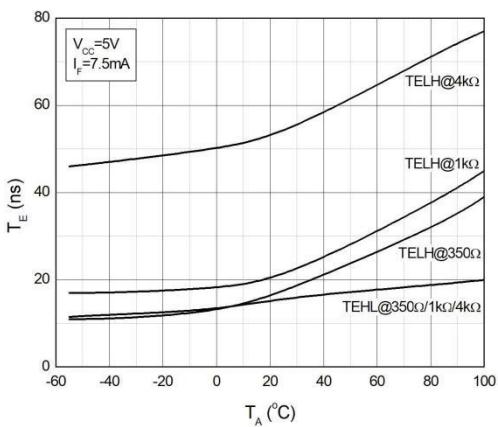
CHARACTERISTIC CURVES



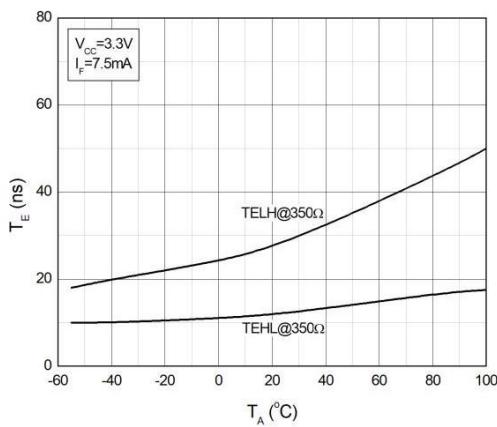
**Fig.19 Pulse Width Distortion
vs. Ambient Temperature**



**Fig.20 Pulse Width Distortion
vs. Ambient Temperature**



**Fig.21 Enable Propagation Delay
vs. Ambient Temperature**



**Fig.22 Enable Propagation Delay
vs. Ambient Temperature**

TEST CIRCUITS

Fig.23 Test Circuits for TPHL, TPLH, tr, t

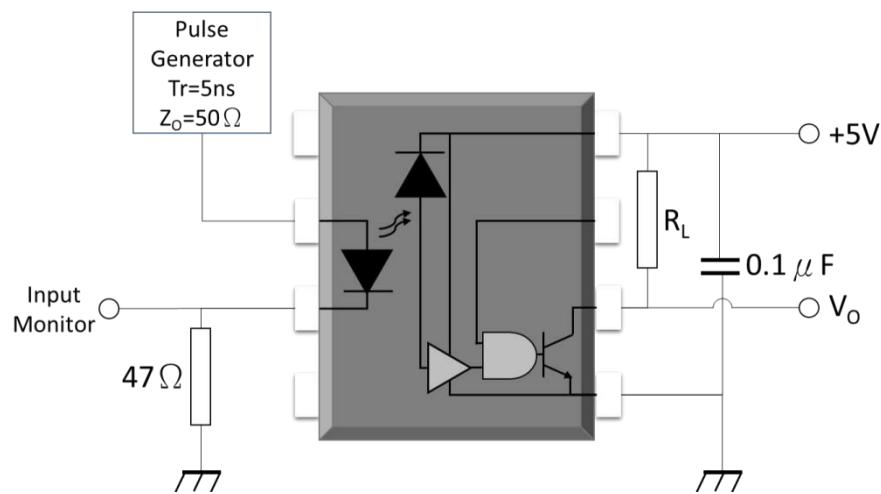
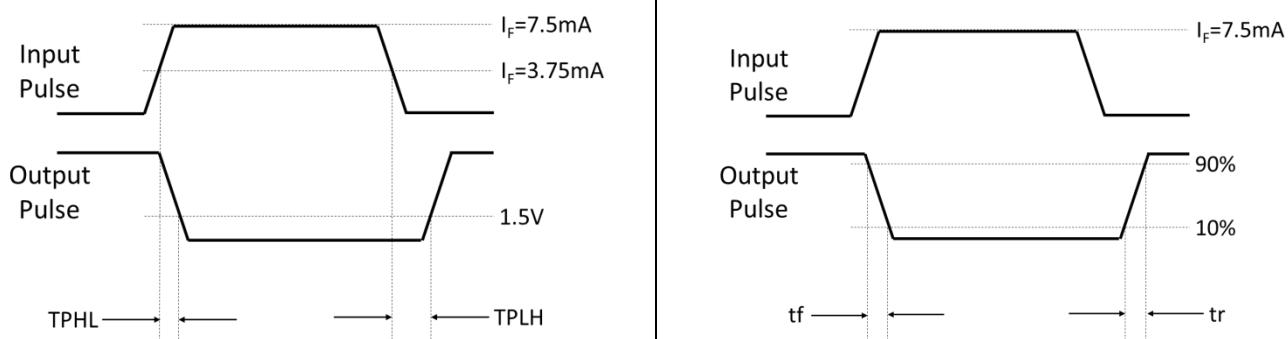


Fig.24 Waveforms of TPHL, TPLH, tr, tf



TEST CIRCUITS

Fig.25 Test Circuits for TEHL, TELH

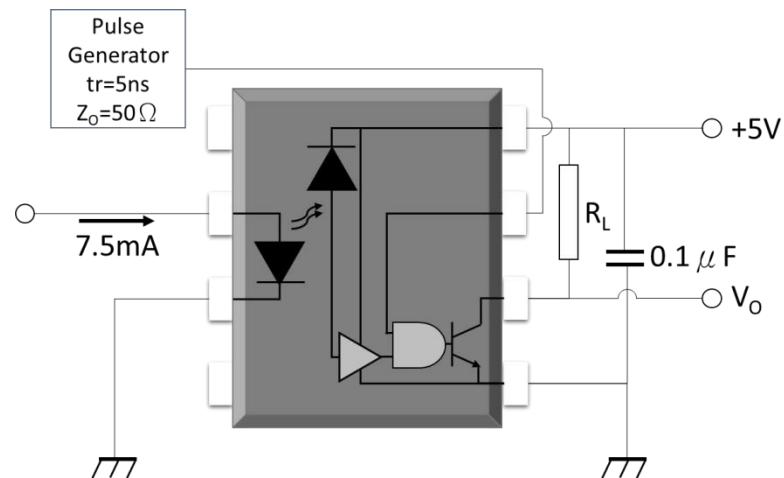
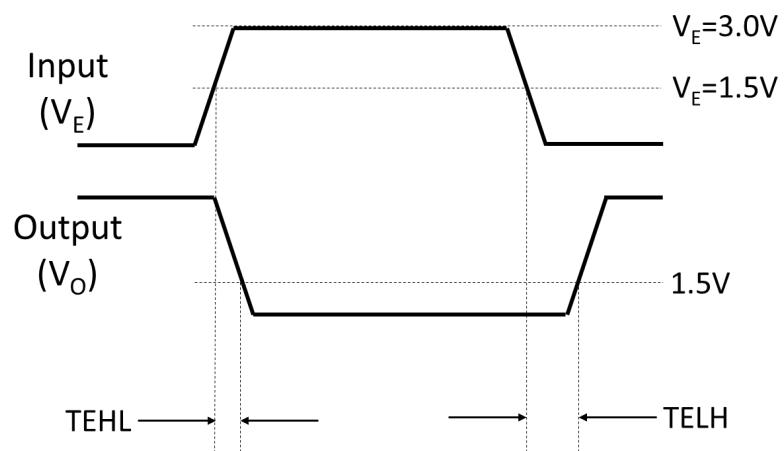


Fig.26 Waveforms of TEHL, TELH



TEST CIRCUITS

Fig.25 Test Circuits for Common Mode Transient Immunity

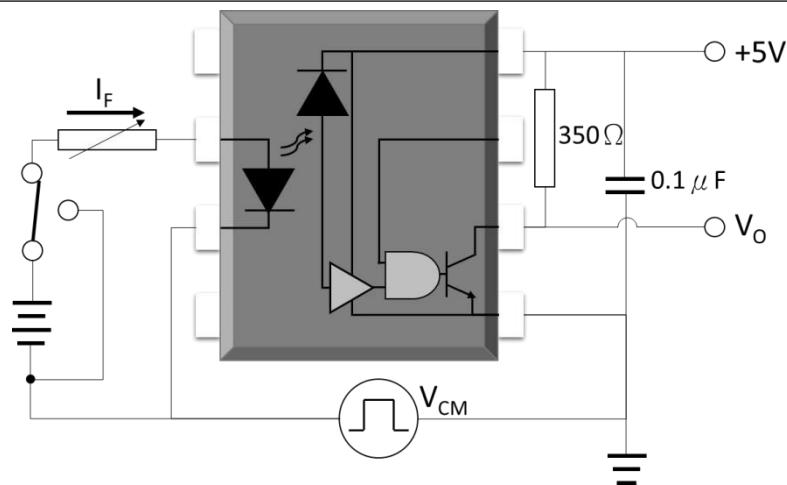
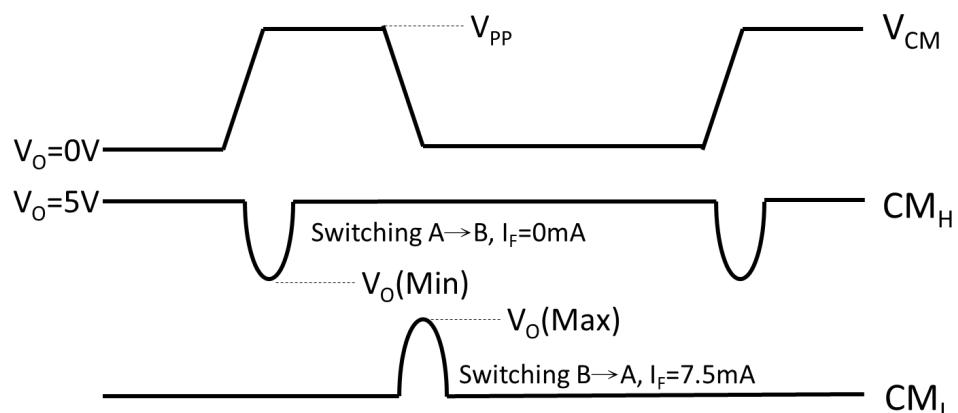
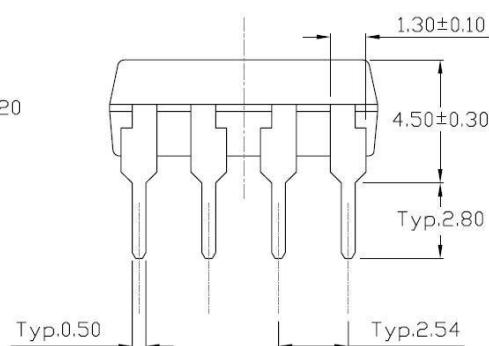
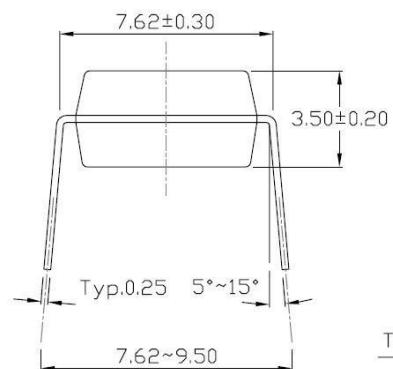
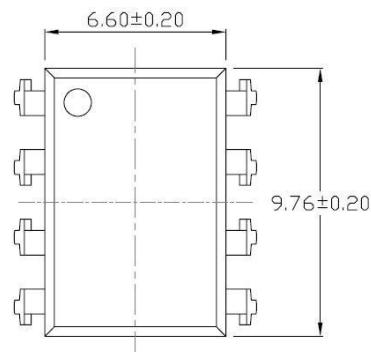
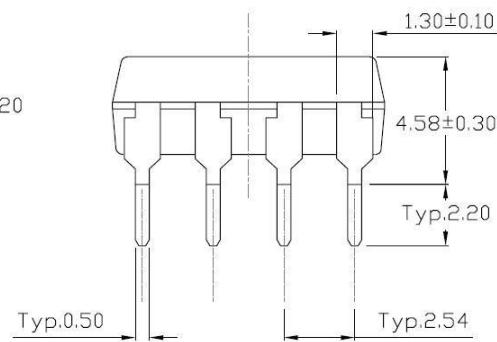
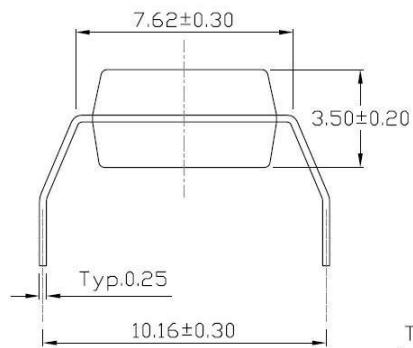
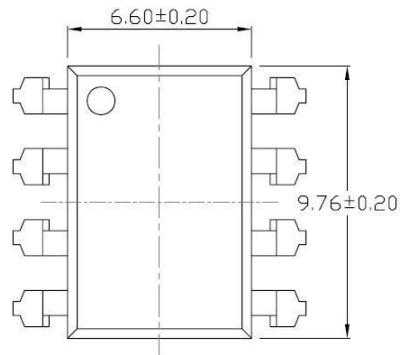
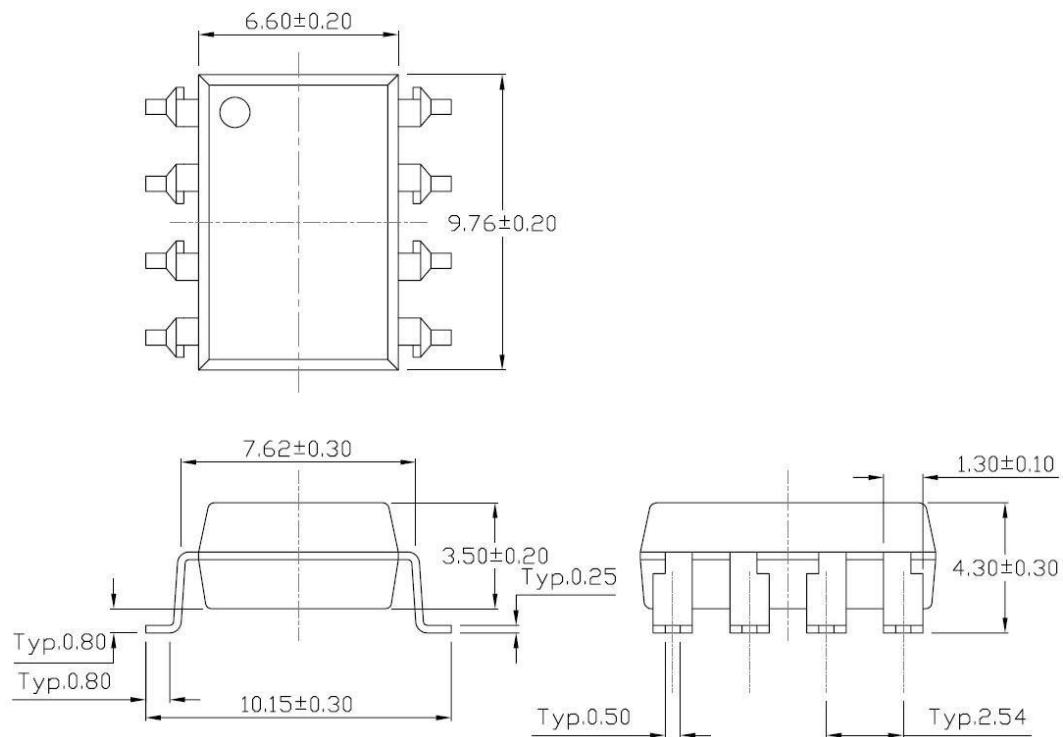
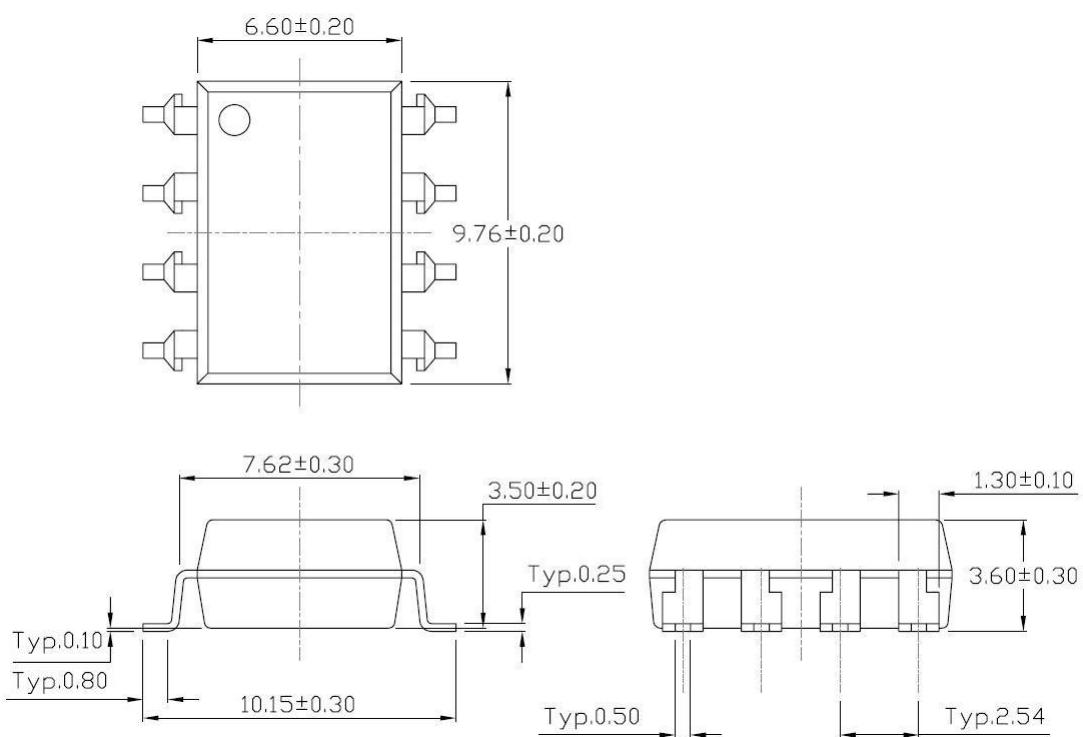
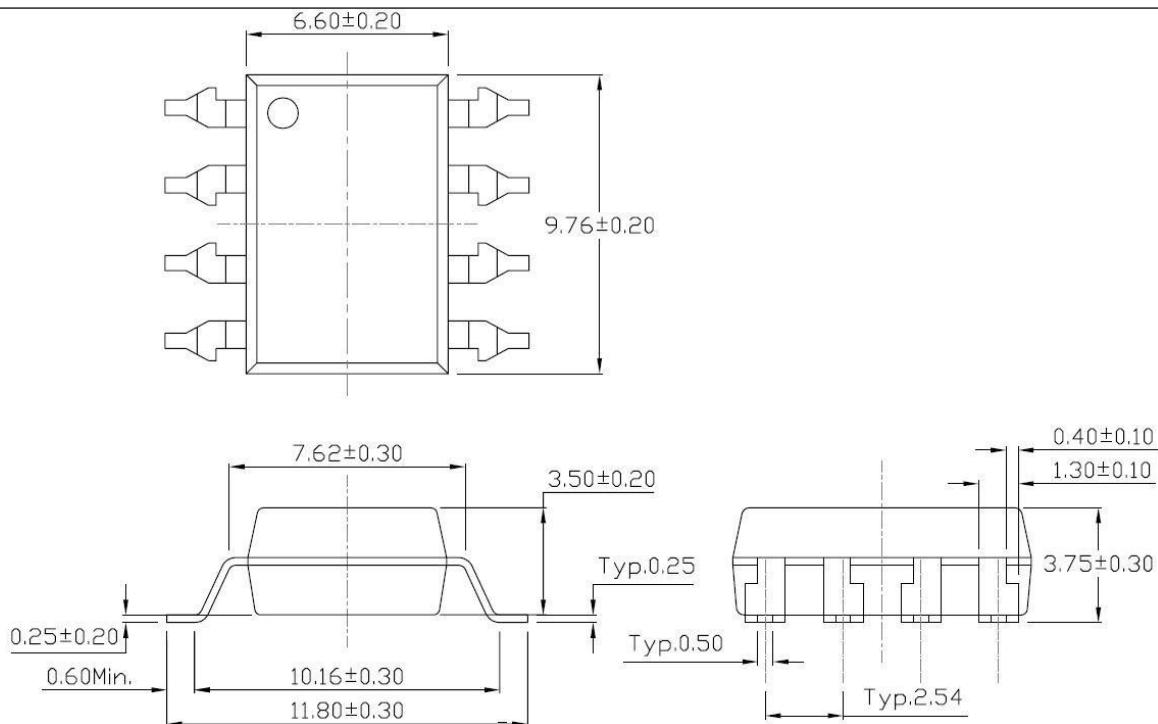
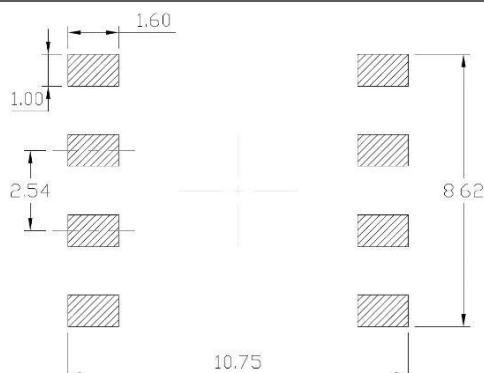
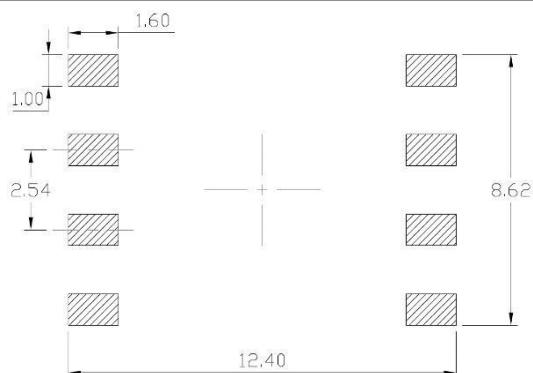


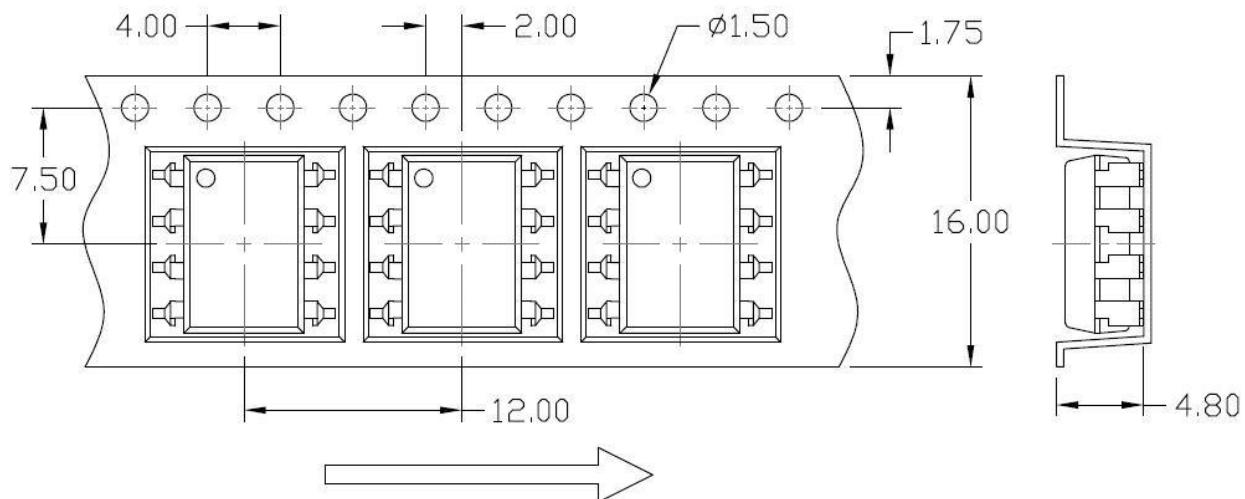
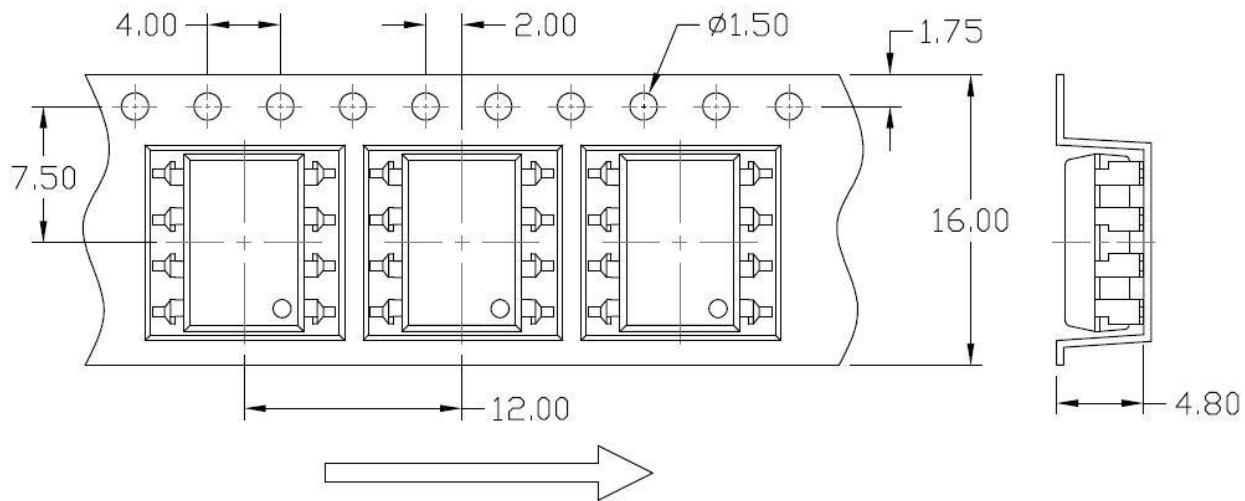
Fig.26 Waveforms of Common Mode Transient Immunity

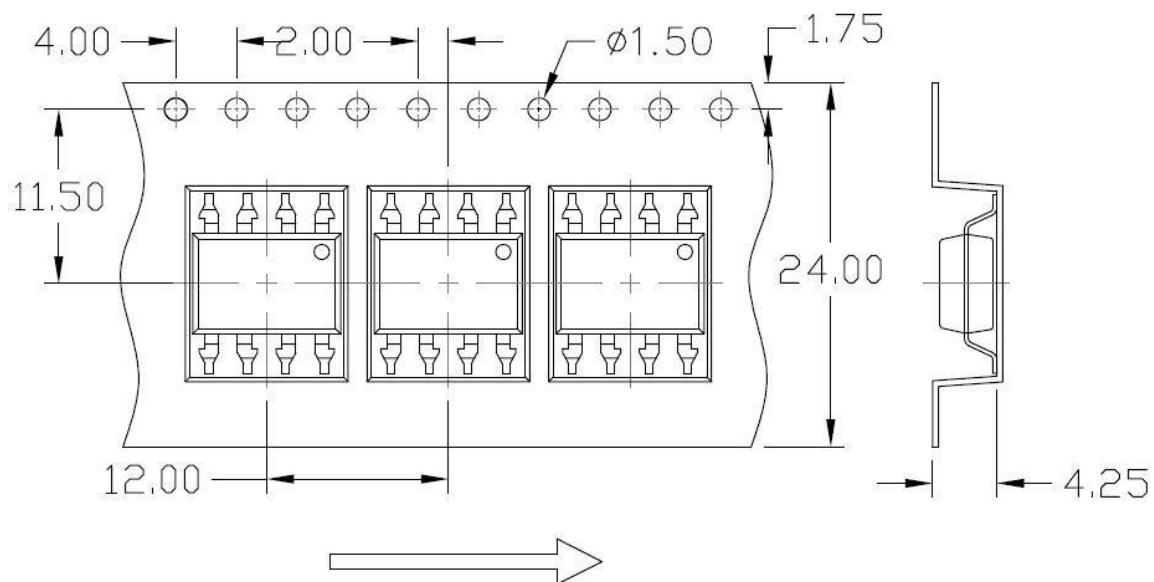
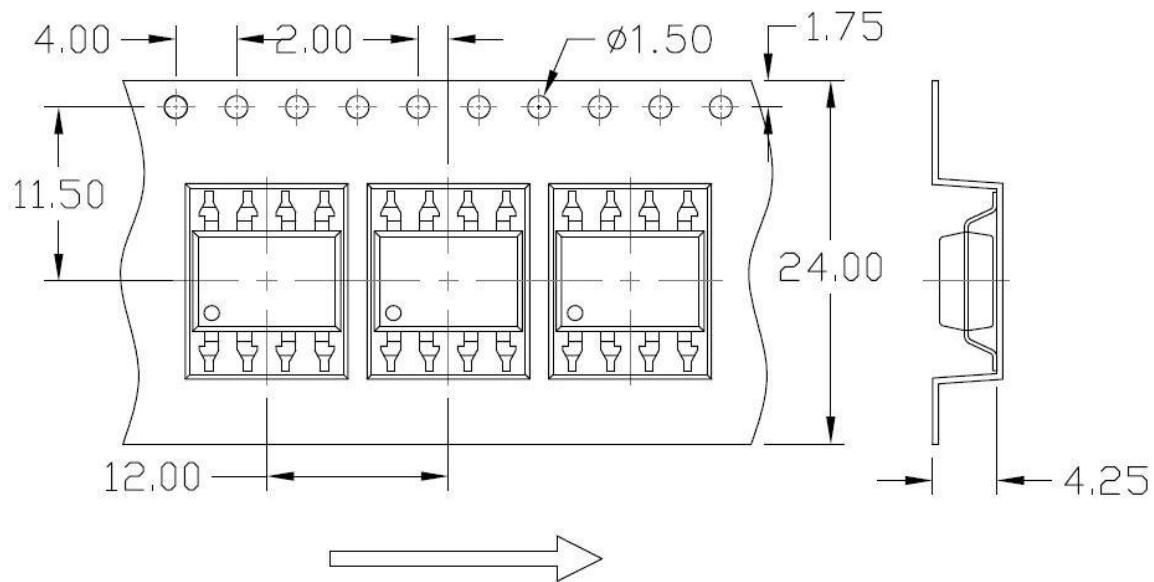


PACKAGE DIMENSIONS (Dimensions in mm unless otherwise stated)
Standard DIP – Through Hole (DIP Type)

Gullwing (400mil) Lead Forming – Through Hole (M Type)


PACKAGE DIMENSIONS (Dimensions in mm unless otherwise stated)
Surface Mount Lead Forming (S Type)

Surface Mount (Low Profile) Lead Forming (SL Type)


PACKAGE DIMENSIONS (Dimensions in mm unless otherwise stated)
Surface Mount (Gullwing) Lead Forming (SLM Type)

Recommended Solder Mask (Dimensions in mm unless otherwise stated)
Surface Mount Lead Forming & Surface Mount (Low Profile) Lead Forming

Surface Mount (Gullwing) Lead Forming


Carrier Tape Specifications (Dimensions in mm unless otherwise stated)
Option S(T1) & SL(T1)

Option S(T2) & SL(T2)


Carrier Tape Specifications (Dimensions in mm unless otherwise stated)
Option SLM(T1)

Option SLM(T2)




ORDERING AND MARKING INFORMATION

MARKING INFORMATION



MPC : Company Abbr.

6N137 : Part Number

V : VDE Option

Y : Fiscal Year

A : Manufacturing Code

WW : Work Week

ORDERING INFORMATION

6N137(Y)(Z)-GV

MPC – Company Abbr.

6N137 – Part Number

Y – Lead Form Option (M/S/SL/SLM/None)

Z – Tape and Reel Option (T1/T2)

G – Material Option (G: Green, None: Non-Green)

V – VDE Option (V or None)

PACKING QUANTITY

Option	Description	Quantity
None	Standard 8 Pin Dip	50Units/Reel
M	Gullwing(400mil) Lead Forming	50Units/Reel
S(T1)	Surface Mount Lead Forming – With Option 1 Taping	1000Units/Tube
S(T2)	Surface Mount Lead Forming – With Option 2 Taping	1000Units/Tube
SL(T1)	Surface Mount Lead Forming(Low Profile) – With Option 1 Taping	1000Units/Tube
SL(T2)	Surface Mount Lead Forming(Low Profile) – With Option 2 Taping	1000Units/Tube



ORDERING AND MARKING INFORMATION

MARKING INFORMATION



MPC : Company Abbr.

26XX : Part Number

V : VDE Option

Y : Fiscal Year

A : Manufacturing Code

WW : Work Week

ORDERING INFORMATION

MPC26XX(Y)(Z)-GV

MPC – Company Abbr.

26XX – Part Number

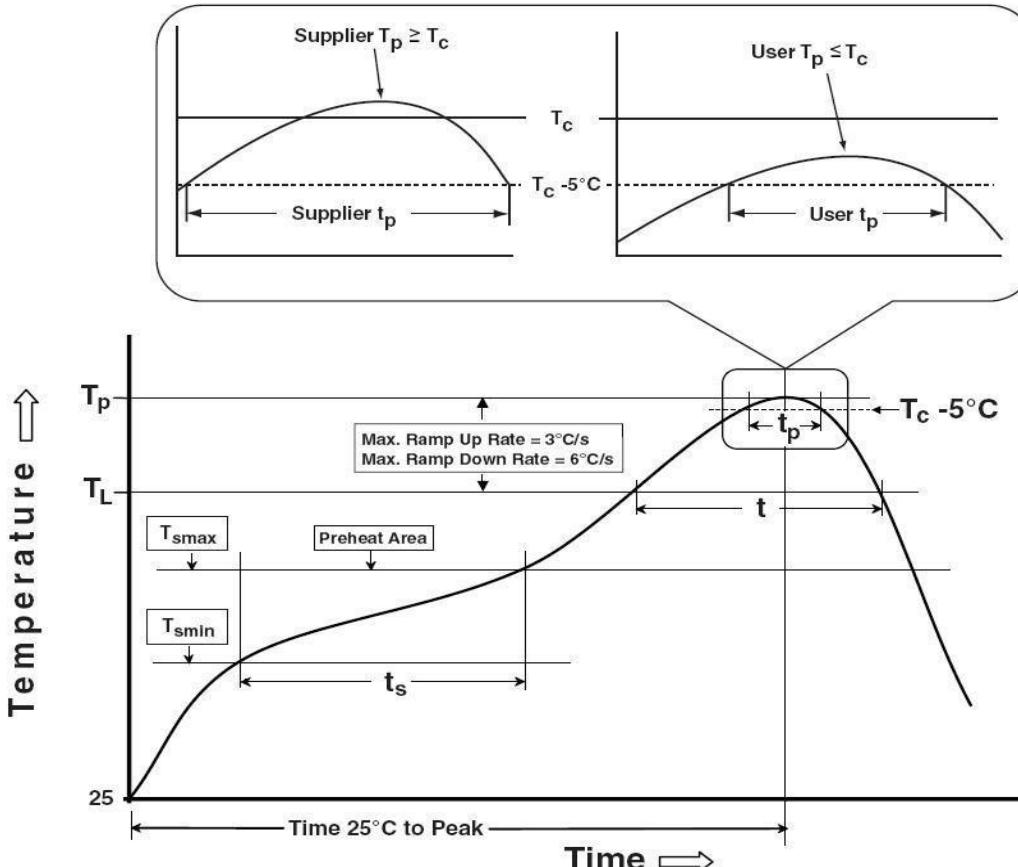
Z – Tape and Reel Option (T1/T2)

G – Material Option (G: Green, None: Non-Green)

V – VDE Option (V or None)

PACKING QUANTITY

Option	Description	Quantity
None	Standard 8 Pin Dip	50Units/Reel
M	Gullwing(400mil) Lead Forming	50Units/Reel
S(T1)	Surface Mount Lead Forming – With Option 1 Taping	1000Units/Tube
S(T2)	Surface Mount Lead Forming – With Option 2 Taping	1000Units/Tube
SL(T1)	Surface Mount Lead Forming(Low Profile) – With Option 1 Taping	1000Units/Tube
SL(T2)	Surface Mount Lead Forming(Low Profile) – With Option 2 Taping	1000Units/Tube

REFLOW INFORMATION
REFLOW PROFILE


IPC-020d-5-1

Profile Feature	Sn-Pb Assembly Profile	Pb-Free Assembly Profile
Temperature Min. (T_{smin})	100	150°C
Temperature Max. (T_{smax})	150	200°C
Time (t_s) from (T_{smin} to T_{smax})	60-120 seconds	60-120 seconds
Ramp-up Rate (t_L to t_p)	3°C/second max.	3°C/second max.
Liquidous Temperature (T_L)	183°C	217°C
Time (t_L) Maintained Above (T_L)	60 – 150 seconds	60 – 150 seconds
Peak Body Package Temperature	$235^\circ\text{C} +0^\circ\text{C} / -5^\circ\text{C}$	$260^\circ\text{C} +0^\circ\text{C} / -5^\circ\text{C}$
Time (t_p) within 5°C of 260°C	20 seconds	30 seconds
Ramp-down Rate (T_p to T_L)	6°C/second max	6°C/second max
Time 25°C to Peak Temperature	6 minutes max.	8 minutes max.

**DISCLAIMER**

- Our company is continually improving the quality, reliability, function and design. Our company reserves the right to make changes without further notices.
- The characteristic curves shown in this datasheet are representing typical performance which are not guaranteed.
- This product is not intended to be used for military, aircraft, automotive, medical, life sustaining or lifesaving applications or any other application which can result in human injury or death.
- Immerge unit's body in solder paste is not recommended.
- Discoloration might be occurred on the package surface after soldering, reflow or long-time use. It neither impacts the performance nor reliability.

■ Revision History

Version	Date	Subjects (major changes since last revision)
1.0	2018-12-21	Datasheet Complete